# 74LVC2G3157

## Dual 10 Ω single-pole double-throw analog switch

Rev. 5 — 21 August 2023 Product data sheet

## 1. General description

The 74LVC2G3157 is a dual low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. Each switch has a digital select input (nS), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ).

Schmitt trigger action at the select inputs makes the circuit tolerant of slower input rise and fall times across the entire $V_{CC}$ range from 1.65 V to 5.5 V.

## 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON resistance:
  - 10.4 Ω (typical) at $V_{CC}$ = 2.7 V
  - 7.8 Ω (typical) at $V_{CC}$ = 3.3 V
  - 6.2 Ω (typical) at $V_{CC}$ = 5 V
- Switch current capability of 32 mA
- Break-before-make switching
- High noise immunity
- CMOS low power consumption
- TTL interface compatibility at 3.3 V
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Select input accepts voltages up to 5.5 V
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

## 3. Ordering information

**Table 1. Ordering information**

| Type number | Package | | | |
|---|---|---|---|---|
| | Temperature range | Name | Description | Version |
| 74LVC2G3157DP | -40 °C to +125 °C | TSSOP10 | plastic thin shrink small outline package; 10 leads; body width 3 mm | SOT552-1 |

## 4. Marking

**Table 2. Marking codes**

| Type number | Marking code[1] |
|---|---|
| 74LVC2G3157DP | YJ |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram

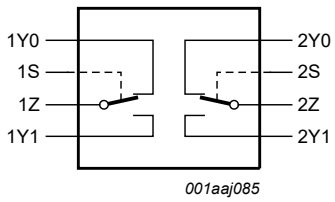



Fig. 1. Logic symbol

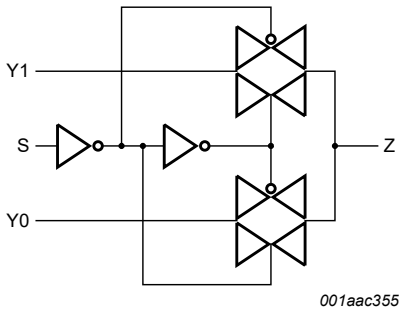



Fig. 2. Logic diagram (one switch)

# 6. Pinning information

## 6.1. Pinning

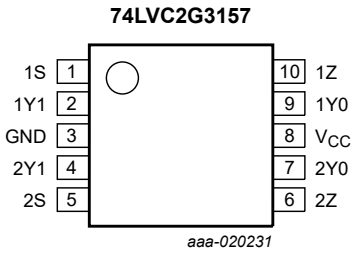



Fig. 3. Pin configuration SOT552-1 (TSSOP10)

## 6.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|---|---|---|
| 1S | 1 | select input |
| 1Y1 | 2 | independent input or output |
| GND | 3 | ground (0 V) |
| 2Y1 | 4 | independent input or output |
| 2S | 5 | select input |
| 2Z | 6 | common output or input |
| 2Y0 | 7 | independent input or output |
| $V_{CC}$ | 8 | supply voltage |
| 1Y0 | 9 | independent input or output |
| 1Z | 10 | common output or input |

# 7. Functional description

**Table 4. Function table**

*H = HIGH voltage level; L = LOW voltage level.*

| Input nS | Channel on |
|---|---|
| L | nY0 |
| H | nY1 |

# 8. Limiting values

**Table 5. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).*

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{CC}$ | supply voltage | | | -0.5 | +6.5 | V |
| $V_I$ | input voltage | | [1] | -0.5 | +6.5 | V |
| $I_{IK}$ | input clamping current | $V_I$ < -0.5 V | | -50 | - | mA |
| $I_{SK}$ | switch clamping current | $V_I$ < -0.5 V or $V_I$ > $V_{CC}$ + 0.5 V | | - | ±50 | mA |
| $V_{SW}$ | switch voltage | enable and disable mode | [2] | -0.5 | $V_{CC}$ + 0.5 | V |
| $I_{SW}$ | switch current | $V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V | | - | ±50 | mA |
| $I_{CC}$ | supply current | | | - | 100 | mA |
| $I_{GND}$ | ground current | | | -100 | - | mA |
| $T_{stg}$ | storage temperature | | | -65 | +150 | °C |
| $P_{tot}$ | total power dissipation | $T_{amb}$ = -40 °C to +125 °C | [3] | - | 250 | mW |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.
[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.
[3] For SOT552-1 (TSSOP10) packages: $P_{tot}$ derates linearly with 8.3 mW/K above 120 °C.

# 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $V_{CC}$ | supply voltage | | | 1.65 | - | 5.5 | V |
| $V_I$ | input voltage | | | 0 | - | 5.5 | V |
| $V_{SW}$ | switch voltage | enable and disable mode | [1] | 0 | - | $V_{CC}$ | V |
| $T_{amb}$ | ambient temperature | | | -40 | - | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | $V_{CC}$ = 1.65 V to 2.7 V | [2] | - | - | 20 | ns/V |
| | | $V_{CC}$ = 2.7 V to 5.5 V | [2] | - | - | 10 | ns/V |

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.
[2] Applies to control signal levels.

# 10. Static characteristics

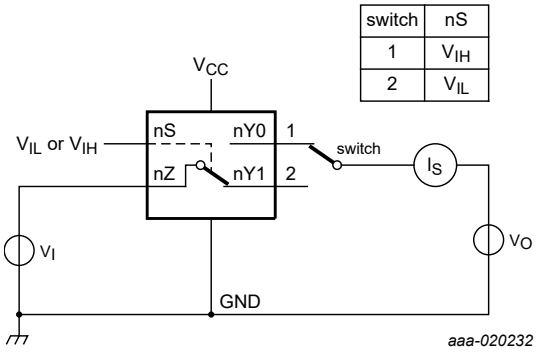
**Table 7. Static characteristics**

*At recommended operating conditions; voltages are referenced to GND (ground 0 V).*

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | Min | Typ[1] | Max | Min | Max | |
| $V_{IH}$ | HIGH-level input voltage | $V_{CC}$ = 1.65 V to 1.95 V | $0.65V_{CC}$ | - | - | $0.65V_{CC}$ | - | V |
| | | $V_{CC}$ = 2.3 V to 2.7 V | 1.7 | - | - | 1.7 | - | V |
| | | $V_{CC}$ = 3 V to 3.6 V | 2.0 | - | - | 2.0 | - | V |
| | | $V_{CC}$ = 4.5 V to 5.5 V | $0.7V_{CC}$ | - | - | $0.7V_{CC}$ | - | V |
| $V_{IL}$ | LOW-level input voltage | $V_{CC}$ = 1.65 V to 1.95 V | - | - | $0.35V_{CC}$ | - | $0.35V_{CC}$ | V |
| | | $V_{CC}$ = 2.3 V to 2.7 V | - | - | 0.7 | - | 0.7 | V |
| | | $V_{CC}$ = 3 V to 3.6 V | - | - | 0.8 | - | 0.8 | V |
| | | $V_{CC}$ = 4.5 V to 5.5 V | - | - | $0.3V_{CC}$ | | $0.3V_{CC}$ | V |
| $I_I$ | input leakage current | pin nS; $V_I$ = 5.5 V or GND; $V_{CC}$ = 0 V to 5.5 V [2] | - | ±0.1 | ±1 | - | ±1 | µA |
| $I_{S(OFF)}$ | OFF-state leakage current | $V_{CC}$ = 5.5 V; see Fig. 4 [2] | - | ±0.1 | ±0.2 | - | ±0.5 | µA |
| $I_{S(ON)}$ | ON-state leakage current | $V_{CC}$ = 5.5 V; see Fig. 5 [2] | - | ±0.1 | ±1 | - | ±2 | µA |
| $I_{CC}$ | supply current | $V_I$ = 5.5 V or GND; $V_{SW}$ = GND or $V_{CC}$; $V_{CC}$ = 1.65 V to 5.5 V [2] | - | 0.1 | 4 | - | 4 | µA |
| $\Delta I_{CC}$ | additional supply current | pin nS; $V_I$ = $V_{CC}$ - 0.6 V; $V_{CC}$ = 5.5 V; $V_{SW}$ = GND or $V_{CC}$ [2] | - | 5 | 500 | - | 500 | µA |
| $C_I$ | input capacitance | | - | 2.5 | - | - | - | pF |
| $C_{S(OFF)}$ | OFF-state capacitance | | - | 6.0 | - | - | - | pF |
| $C_{S(ON)}$ | ON-state capacitance | | - | 18 | - | - | - | pF |

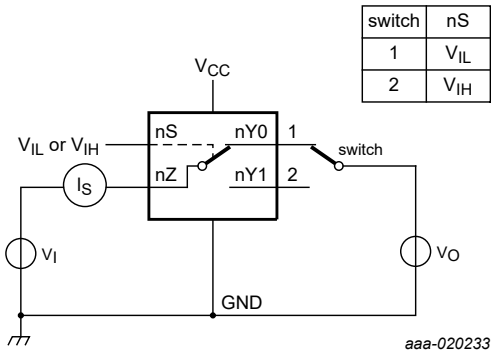
[1] Typical values are measured at $T_{amb}$ = 25 °C.
[2] These typical values are measured at $V_{CC}$ = 3.3 V

## 10.1. Test circuits




$V_I$ = $V_{CC}$ or GND and $V_O$ = GND or $V_{CC}$.

**Fig. 4. Test circuit for measuring OFF-state leakage current**




$V_I$ = $V_{CC}$ or GND and $V_O$ = open circuit.

**Fig. 5. Test circuit for measuring ON-state leakage current**

## 10.2. ON resistance

**Table 8. ON resistance**

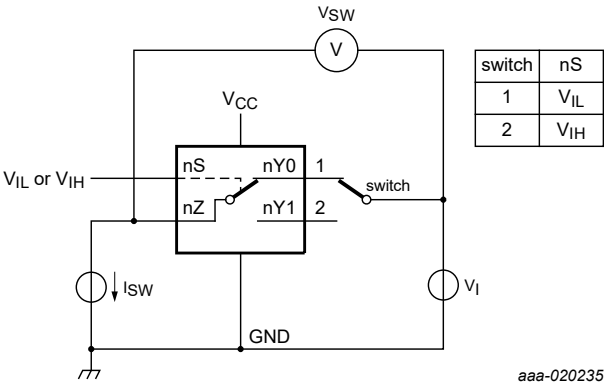
*At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Fig. 7 to Fig. 12.*

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | Min | Typ[1] | Max | Min | Max | |
| $R_{ON(peak)}$ | ON resistance (peak) | $V_I$ = GND to $V_{CC}$; see Fig. 6 | | | | | | |
| | | $I_{SW}$ = 4 mA;$V_{CC}$ = 1.65 V to 1.95 V | - | 34.0 | 130 | - | 195 | Ω |
| | | $I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V | - | 12.0 | 30 | - | 45 | Ω |
| | | $I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V | - | 10.4 | 25 | - | 38 | Ω |
| | | $I_{SW}$ = 24 mA; $V_{CC}$ = 3.0 V to 3.6 V | - | 7.8 | 20 | - | 30 | Ω |
| | | $I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V | - | 6.2 | 15 | - | 23 | Ω |
| $R_{ON(rail)}$ | ON resistance (rail) | $V_I$ = GND; see Fig. 6 | | | | | | |
| | | $I_{SW}$ = 4 mA;$V_{CC}$ = 1.65 V to 1.95 V | - | 8.2 | 18 | - | 27 | Ω |
| | | $I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V | - | 7.1 | 16 | - | 24 | Ω |
| | | $I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V | - | 6.9 | 14 | - | 21 | Ω |
| | | $I_{SW}$ = 24 mA; $V_{CC}$ = 3.0 V to 3.6 V | - | 6.5 | 12 | - | 18 | Ω |
| | | $I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V | - | 5.8 | 10 | - | 15 | Ω |
| | | $V_I$ = $V_{CC}$; see Fig. 6 | | | | | | |
| | | $I_{SW}$ = 4 mA;$V_{CC}$ = 1.65 V to 1.95 V | - | 10.4 | 30 | - | 45 | Ω |
| | | $I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V | - | 7.6 | 20 | - | 30 | Ω |
| | | $I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V | - | 7.0 | 18 | - | 27 | Ω |
| | | $I_{SW}$ = 24 mA; $V_{CC}$ = 3.0 V to 3.6 V | - | 6.1 | 15 | - | 23 | Ω |
| | | $I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V | - | 4.9 | 10 | - | 15 | Ω |

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | Min | Typ[1] | Max | Min | Max | |
| $R_{ON(flat)}$ | ON resistance (flatness) | $V_I$ = GND to $V_{CC}$ [2] | | | | | | |
| | | $I_{SW}$ = 4 mA;$V_{CC}$ = 1.65 V to 1.95 V | - | 26.0 | - | - | - | Ω |
| | | $I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V | - | 5.0 | - | - | - | Ω |
| | | $I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V | - | 3.5 | - | - | - | Ω |
| | | $I_{SW}$ = 24 mA; $V_{CC}$ = 3.0 V to 3.6 V | - | 2.0 | - | - | - | Ω |
| | | $I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V | - | 1.5 | - | - | - | Ω |

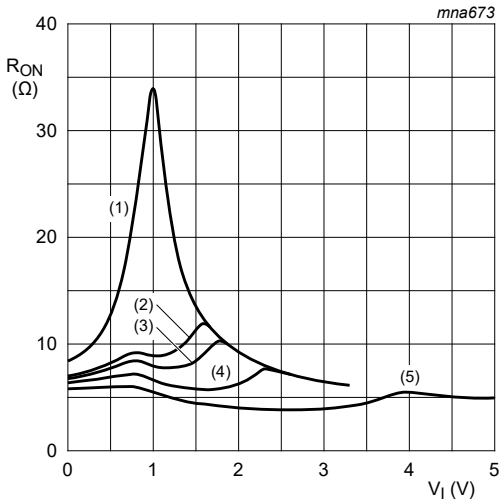
[1] Typical values are measured at $T_{amb}$ = 25 °C and nominal $V_{CC}$.
[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical $V_{CC}$ and temperature.

## 10.3. ON resistance test circuit and graphs



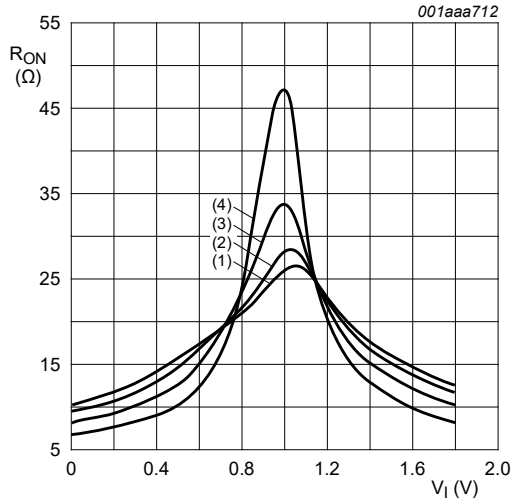

$R_{ON} = V_{SW}/I_{SW}$.

**Fig. 6. Test circuit for measuring ON resistance**



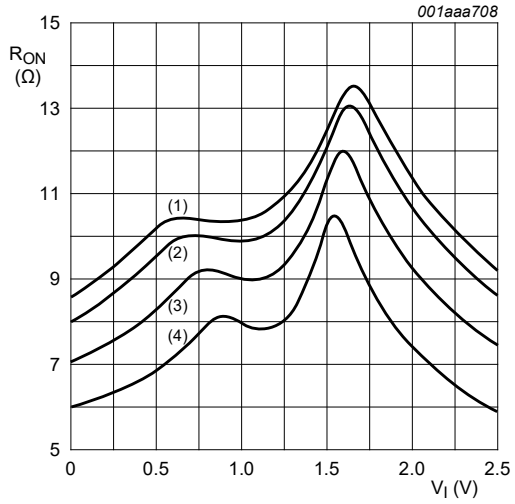

(1) $V_{CC}$ = 1.8 V.
(2) $V_{CC}$ = 2.5 V.
(3) $V_{CC}$ = 2.7 V.
(4) $V_{CC}$ = 3.3 V.
(5) $V_{CC}$ = 5.0 V.

**Fig. 7. Typical ON resistance as a function of input voltage; $T_{amb}$ = 25 °C**



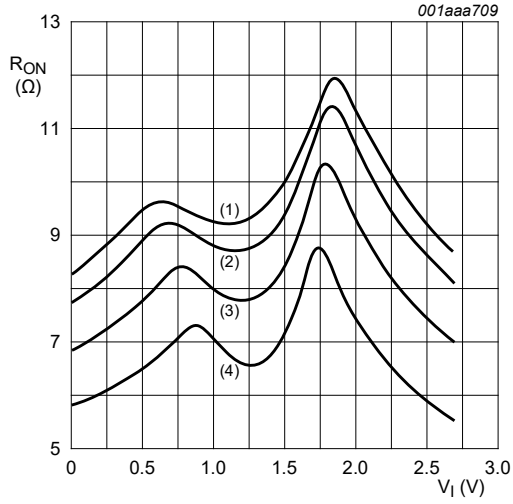

(1) $T_{amb}$ = 125 °C.
(2) $T_{amb}$ = 85 °C.
(3) $T_{amb}$ = 25 °C.
(4) $T_{amb}$ = -40 °C.

**Fig. 8. ON resistance as a function of input voltage; $V_{CC}$ = 1.8 V**



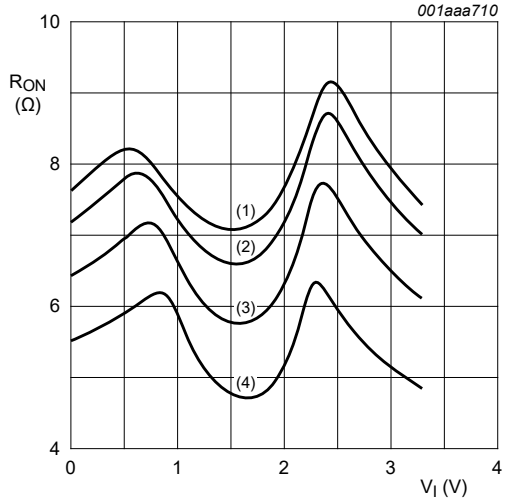

(1) $T_{amb}$ = 125 °C.
(2) $T_{amb}$ = 85 °C.
(3) $T_{amb}$ = 25 °C.
(4) $T_{amb}$ = -40 °C.

**Fig. 9. ON resistance as a function of input voltage; $V_{CC}$ = 2.5 V**



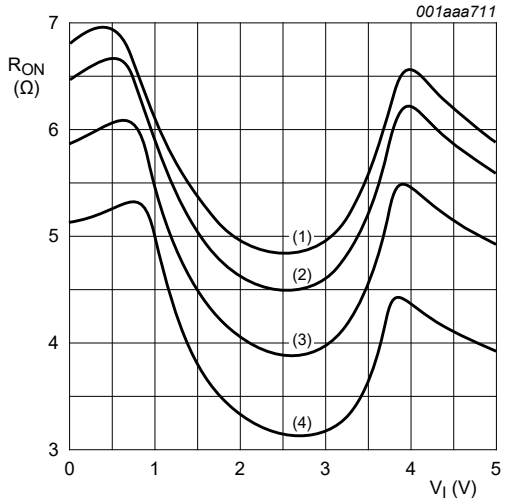

(1) $T_{amb}$ = 125 °C.
(2) $T_{amb}$ = 85 °C.
(3) $T_{amb}$ = 25 °C.
(4) $T_{amb}$ = -40 °C.

**Fig. 10. ON resistance as a function of input voltage; $V_{CC}$ = 2.7 V**




(1) $T_{amb}$ = 125 °C.
(2) $T_{amb}$ = 85 °C.
(3) $T_{amb}$ = 25 °C.
(4) $T_{amb}$ = -40 °C.

**Fig. 11. ON resistance as a function of input voltage; $V_{CC}$ = 3.3 V**




(1) $T_{amb}$ = 125 °C.
(2) $T_{amb}$ = 85 °C.
(3) $T_{amb}$ = 25 °C.
(4) $T_{amb}$ = -40 °C.

**Fig. 12. ON resistance as a function of input voltage; $V_{CC}$ = 5.0 V**

# 11. Dynamic characteristics

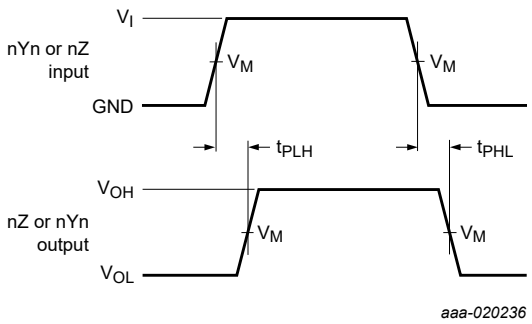
**Table 9. Dynamic characteristics**

*At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 16.*

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | Min | Typ[1] | Max | Min | Max | |
| $t_{pd}$ | propagation delay | nYn to nZ or nZ to nYn; see Fig. 13 [2][3] | | | | | | |
| | | $V_{CC}$ = 1.65 V to 1.95 V | - | - | 2 | - | 3.0 | ns |
| | | $V_{CC}$ = 2.3 V to 2.7 V | - | - | 1.2 | - | 2.0 | ns |
| | | $V_{CC}$ = 2.7 V | - | - | 1.0 | - | 1.5 | ns |
| | | $V_{CC}$ = 3.0 V to 3.6 V | - | - | 0.8 | - | 1.5 | ns |
| | | $V_{CC}$ = 4.5 V to 5.5 V | - | - | 0.6 | - | 1.0 | ns |
| $t_{en}$ | enable time | nS to nYn; see Fig. 14 [4] | | | | | | |
| | | $V_{CC}$ = 1.65 V to 1.95 V | 1 | 8.7 | 24 | 1 | 26.5 | ns |
| | | $V_{CC}$ = 2.3 V to 2.7 V | 1 | 5.3 | 14 | 1 | 15.5 | ns |
| | | $V_{CC}$ = 2.7 V | 1 | 4.9 | 14 | 1 | 15.5 | ns |
| | | $V_{CC}$ = 3.0 V to 3.6 V | 0.5 | 4 | 7.6 | 0.5 | 8.5 | ns |
| | | $V_{CC}$ = 4.5 V to 5.5 V | 0.5 | 3 | 5.7 | 0.5 | 6.6 | ns |
| $t_{dis}$ | disable time | nS to nYn; see Fig. 14 [5] | | | | | | |
| | | $V_{CC}$ = 1.65 V to 1.95 V | 2.5 | 6 | 13 | 2.5 | 14.5 | ns |
| | | $V_{CC}$ = 2.3 V to 2.7 V | 2 | 4.4 | 7.5 | 2 | 8.5 | ns |
| | | $V_{CC}$ = 2.7 V | 1.5 | 4.2 | 7.5 | 1.5 | 8.5 | ns |
| | | $V_{CC}$ = 3.0 V to 3.6 V | 1.5 | 3.6 | 5.3 | 1.5 | 6 | ns |
| | | $V_{CC}$ = 4.5 V to 5.5 V | 0.8 | 2.9 | 3.8 | 0.8 | 4.5 | ns |
| $t_{b-m}$ | break-before-make time | $C_L$ = 35 pF; $R_L$ = 50 Ω; see Fig. 15 [6] | | | | | | |
| | | $V_{CC}$ = 1.65 V to 1.95 V | 0.5 | - | - | 0.5 | - | ns |
| | | $V_{CC}$ = 2.3 V to 2.7 V | 0.5 | - | - | 0.5 | - | ns |
| | | $V_{CC}$ = 2.7 V | 0.5 | - | - | 0.5 | - | ns |
| | | $V_{CC}$ = 3 V to 3.6 V | 0.5 | - | - | 0.5 | - | ns |
| | | $V_{CC}$ = 4.5 V to 5.5 V | 0.5 | - | - | 0.5 | - | ns |

[1] Typical values are measured at $T_{amb}$ = 25 °C and nominal $V_{CC}$.
[2] $t_{pd}$ is the same as $t_{PLH}$ and $t_{PHL}$.
[3] Propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).
[4] $t_{en}$ is the same as $t_{PZH}$ and $t_{PZL}$.
[5] $t_{dis}$ is the same as $t_{PLZ}$ and $t_{PHZ}$.
[6] Break-before-make specified by design.

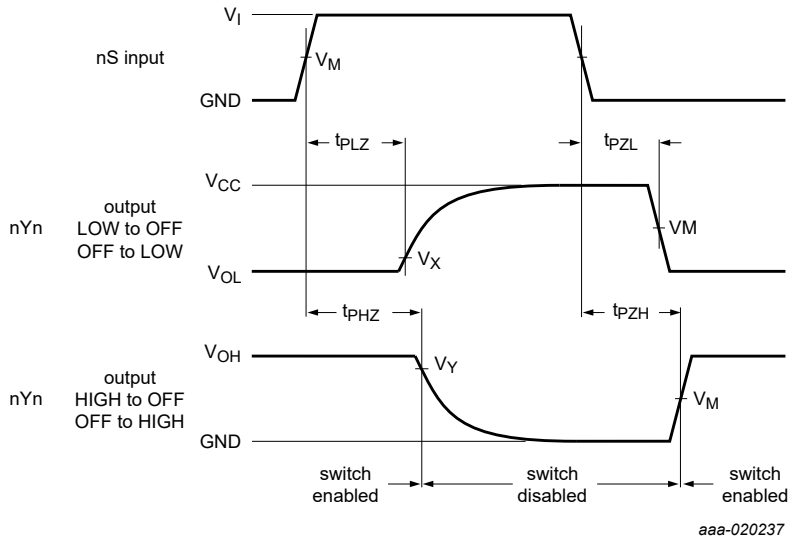
## 11.1. Waveforms and test circuits




Measurement points are given in Table 10.

Logic levels: $V_{OL}$ and $V_{OH}$ are typical output voltage levels that occur with the output load.

**Fig. 13. Input (nYn or nZ) to output (nZ or nYn) propagation delays**



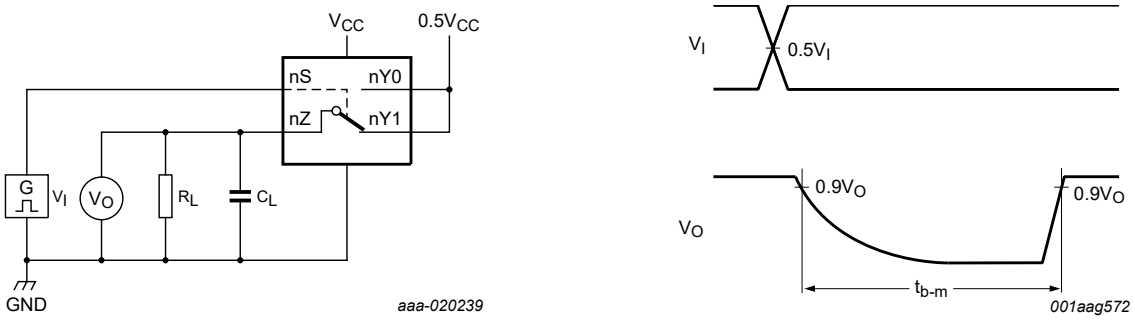

Measurement points are given in Table 10.

Logic levels: $V_{OL}$ and $V_{OH}$ are typical output voltage levels that occur with the output load.

**Fig. 14. Enable and disable times**

**Table 10. Measurement points**

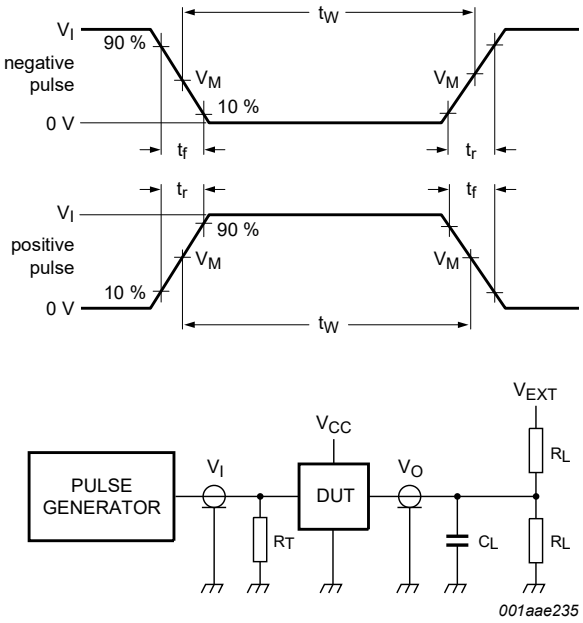
| Supply voltage | Input | Output | | |
|---|---|---|---|---|
| $V_{CC}$ | $V_M$ | $V_M$ | $V_X$ | $V_Y$ |
| 1.65 V to 5.5 V | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL}$ + 0.3 V | $V_{OH}$ - 0.3 V |




a. Test circuit

b. Input and output measurement points

**Fig. 15. Test circuit for measuring break-before-make timing**




Test data is given in Table 11.

Definitions for test circuit:

$R_L$ = Load resistance.

$C_L$ = Load capacitance including jig and probe capacitance.

$R_T$ = Termination resistance should be equal to output impedance $Z_o$ of the pulse generator.

$V_{EXT}$ = Test voltage for switching times.

**Fig. 16. Test circuit for measuring switching times**

**Table 11. Test data**

| Supply voltage | Input | | Load | | $V_{EXT}$ | | |
|---|---|---|---|---|---|---|---|
| $V_{CC}$ | $V_I$ | $t_r$, $t_f$ | $C_L$ | $R_L$ | $t_{PLH}$, $t_{PHL}$ | $t_{PZH}$, $t_{PHZ}$ | $t_{PZL}$, $t_{PLZ}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | ≤ 2.0 ns | 50 pF | 500 Ω | open | GND | $2V_{CC}$ |
| 2.3 V to 2.7 V | $V_{CC}$ | ≤ 2.0 ns | 50 pF | 500 Ω | open | GND | $2V_{CC}$ |
| 2.7 V | $V_{CC}$ | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | $2V_{CC}$ |
| 3 V to 3.6 V | $V_{CC}$ | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | $2V_{CC}$ |
| 4.5 V to 5.5 V | $V_{CC}$ | ≤ 2.5 ns | 50 pF | 500 Ω | open | GND | $2V_{CC}$ |

## 11.2. Additional dynamic characteristics

**Table 12. Additional dynamic characteristics**

*At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $T_{amb}$ = 25 °C.*

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| THD | total harmonic distortion | $f_i$ = 600 Hz to 20 kHz; $R_L$ = 600 Ω; $C_L$ = 50 pF; $V_I$ = 0.5 V (p-p); see Fig. 17 | | | | |
| | | $V_{CC}$ = 1.65 V | - | 0.260 | - | % |
| | | $V_{CC}$ = 2.3 V | - | 0.078 | - | % |
| | | $V_{CC}$ = 3.0 V | - | 0.078 | - | % |
| | | $V_{CC}$ = 4.5 V | - | 0.078 | - | % |
| $f_{(-3dB)}$ | -3 dB frequency response | $R_L$ = 50 Ω; see Fig. 18 | | | | |
| | | $V_{CC}$ = 1.65 V | - | 200 | - | MHz |
| | | $V_{CC}$ = 2.3 V | - | 300 | - | MHz |
| | | $V_{CC}$ = 3.0 V | - | 300 | - | MHz |
| | | $V_{CC}$ = 4.5 V | - | 300 | - | MHz |
| $\alpha_{iso}$ | isolation (OFF-state) | $R_L$ = 50 Ω; $C_L$ = 5 pF; $f_i$ = 10 MHz; see Fig. 19 | | | | |
| | | $V_{CC}$ = 1.65 V | - | -42 | - | dB |
| | | $V_{CC}$ = 2.3 V | - | -42 | - | dB |
| | | $V_{CC}$ = 3.0 V | - | -40 | - | dB |
| | | $V_{CC}$ = 4.5 V | - | -40 | - | dB |
| Xtalk | crosstalk | between switches; $f_i$ = 10 MHz; see Fig. 20 | | | | |
| | | $V_{CC}$ = 1.65 V | - | -54 | - | dB |
| | | $V_{CC}$ = 2.3 V | - | -54 | - | dB |
| | | $V_{CC}$ = 3.0 V | - | -54 | - | dB |
| | | $V_{CC}$ = 4.5 V | - | -54 | - | dB |
| $Q_{inj}$ | charge injection | $C_L$ = 0.1 nF; $V_{gen}$ = 0 V; $R_{gen}$ = 0 Ω; $f_i$ = 1 MHz; $R_L$ = 1 MΩ; see Fig. 21 | | | | |
| | | $V_{CC}$ = 1.8 V | - | 3.3 | - | pC |
| | | $V_{CC}$ = 2.5 V | - | 4.1 | - | pC |
| | | $V_{CC}$ = 3.3 V | - | 5.0 | - | pC |
| | | $V_{CC}$ = 4.5 V | - | 6.4 | - | pC |
| | | $V_{CC}$ = 5.5 V | - | 7.5 | - | pC |

## 11.3. Test circuits

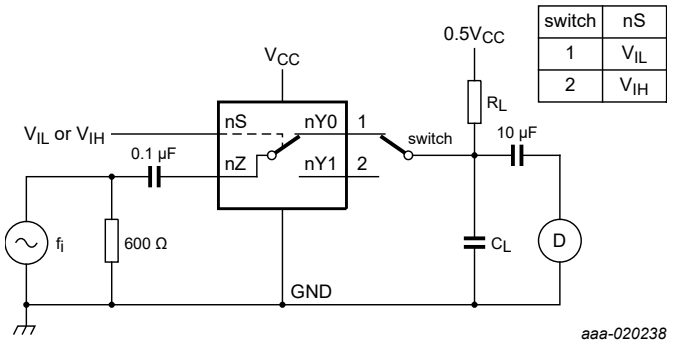
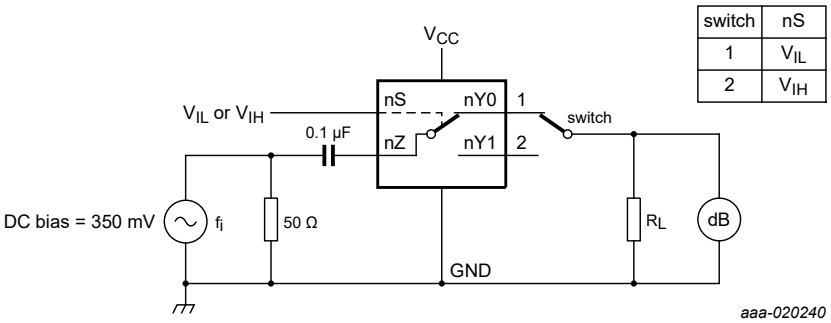
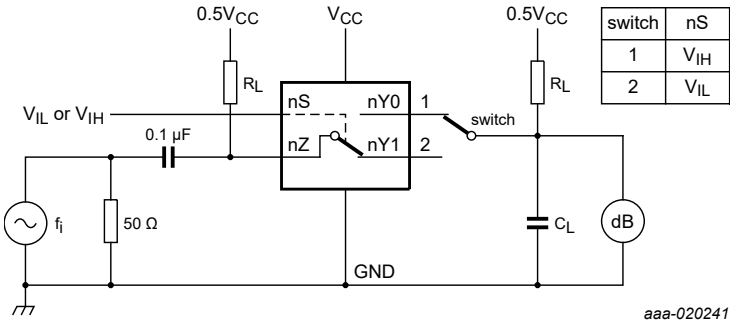



**Fig. 17. Test circuit for measuring total harmonic distortion**



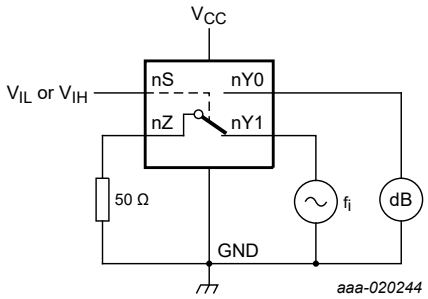

Adjust $f_i$ voltage to obtain 0 dBm level at output. Increase $f_i$ frequency until dB meter reads -3 dB.

**Fig. 18. Test circuit for measuring the frequency response when switch is in ON-state**



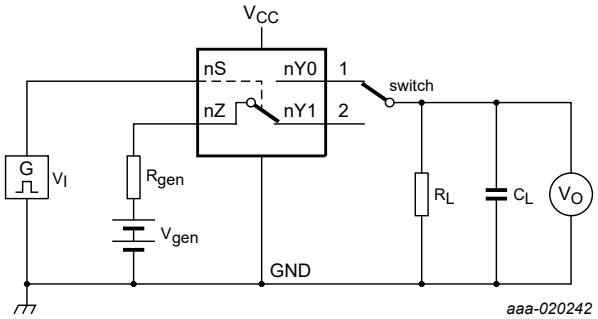

Adjust $f_i$ voltage to obtain 0 dBm level at input.

**Fig. 19. Test circuit for measuring isolation (OFF-state)**

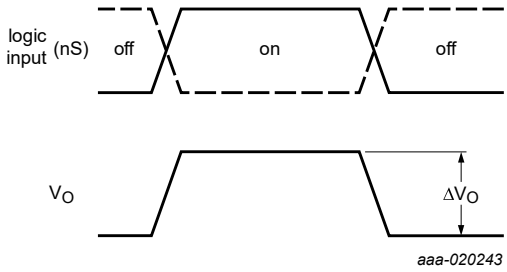



Adjust $f_i$ voltage to obtain 0 dBm level at input.

**Fig. 20. Test circuit for measuring crosstalk**




a. Test circuit



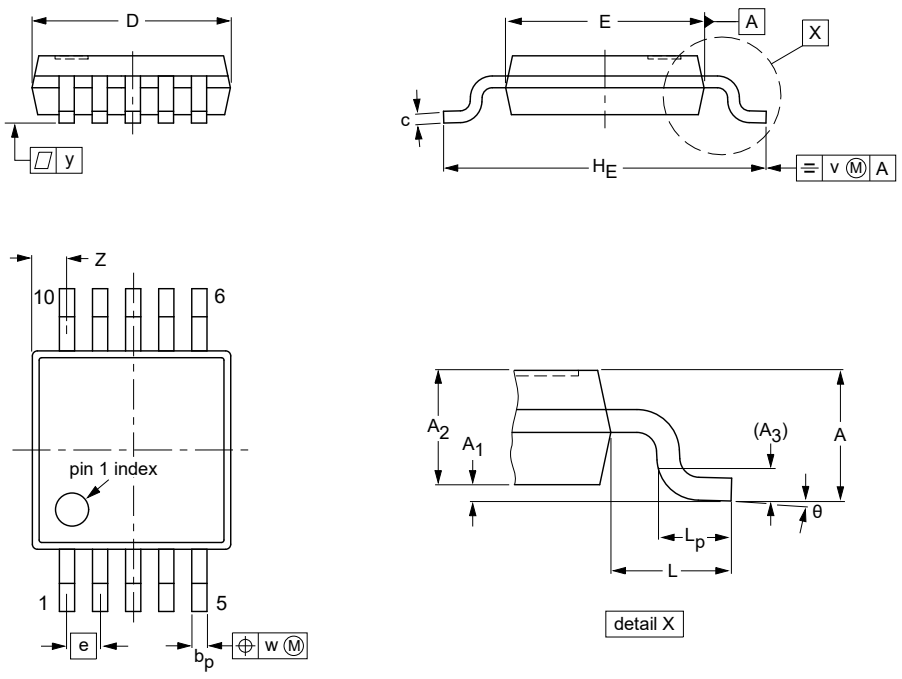

b. Input and output pulse definitions

$Q_{inj} = \Delta V_O \times C_L$.
$\Delta V_O$ = output voltage variation.
$R_{gen}$ = generator resistance.
$V_{gen}$ = generator voltage.

**Fig. 21. Test circuit for measuring charge injection**

## 12. Package outline

**TSSOP10: plastic thin shrink small outline package; 10 leads; body width 3 mm** **SOT552-1**




**DIMENSIONS (mm are the original dimensions)**

| UNIT | A max. | $A_1$ | $A_2$ | $A_3$ | $b_p$ | c | $D^{(1)}$ | $E^{(2)}$ | e | $H_E$ | L | $L_p$ | v | w | y | $Z^{(1)}$ | θ |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| mm | 1.1 | 0.15<br>0.05 | 0.95<br>0.80 | 0.25 | 0.30<br>0.15 | 0.23<br>0.15 | 3.1<br>2.9 | 3.1<br>2.9 | 0.5 | 5.0<br>4.8 | 0.95 | 0.7<br>0.4 | 0.1 | 0.1 | 0.1 | 0.67<br>0.34 | 6°<br>0° |

**Notes**

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|---|---|---|---|---|---|---|
| | IEC | JEDEC | JEITA | | | |
| SOT552-1 | | | | | | ~~99-07-29~~<br>03-02-18 |

**Fig. 22. Package outline SOT552-1 (TSSOP10)**

# 13. Abbreviations

**Table 13. Abbreviations**

| Acronym | Description |
|---|---|
| CDM | Charged Device Model |
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| TTL | Transistor-Transistor Logic |

# 14. Revision history

**Table 14. Revision history**

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---|---|---|---|---|
| 74LVC2G3157 v.5 | 20230822 | Product data sheet | - | 74LVC2G3157 v.4 |
| Modifications: | • Section 2: ESD specification updated according to the latest JEDEC standard. | | | |
| 74LVC2G3157 v.4 | 20210512 | Product data sheet | - | 74LVC2G3157 v.3 |
| Modifications: | • Type number 74LVC2G3157GM (SOT1049-3 / XQFN10) removed.<br>• Section 8: Derating values for $P_{tot}$ total power dissipation updated. | | | |
| 74LVC2G3157 v.3 | 20190325 | Product data sheet | - | 74LVC2G3157 v.2 |
| Modifications: | • The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.<br>• Legal texts have been adapted to the new company name where appropriate. | | | |
| 74LVC2G3157 v.2 | 20161215 | Product data sheet | - | 74LVC2G3157 v.1 |
| Modifications: | • Table 7: The maximum limits for leakage current and supply current have changed. | | | |
| 74LVC2G3157 v.1 | 20151214 | Product data sheet | - | - |

# 15. Legal information

## Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|---|---|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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**Date of release: 21 August 2023**